8-input multiplexer Rev. 4 — 11 February 2013

1. **General description**

The 74HC151; 74HCT151 are 8-bit multiplexer with eight binary inputs (I0 to I7), three select inputs (S0 to S2) and an enable input (E). One of the eight binary inputs is selected by the select inputs and routed to the complementary outputs (Y and \overline{Y}). A HIGH on \overline{E} forces the output Y LOW and output \overline{Y} HIGH. Inputs also include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

Features and benefits 2.

- Input levels:
 - For 74HC151: CMOS level
 - For 74HCT151: TTL level
- Low-power dissipation
- Non-inverting data path
- Specified in compliance with JEDEC standard no. 7A
- ESD protection:
 - HBM JESD22-A114F exceeds 2 000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

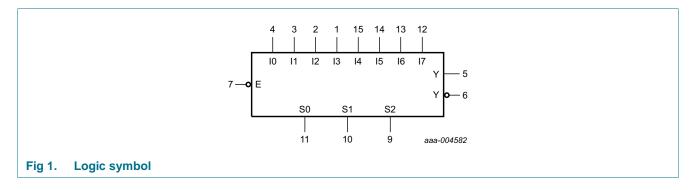
Ordering information 3.

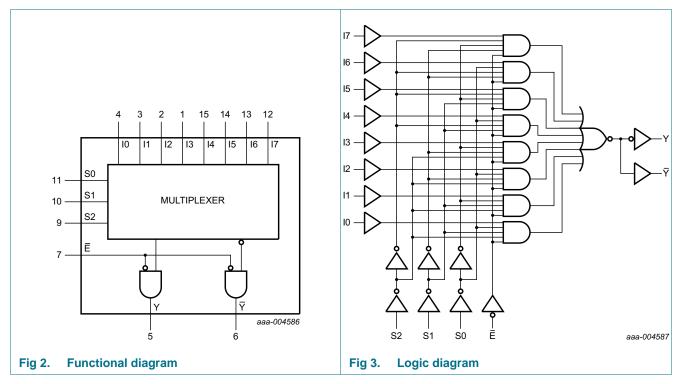
Table 1.	Ordering information
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Type number	Package										
	Temperature range	Name	Description	Version							
74HC151N	–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4							
74HCT151N											
74HC151D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width	SOT109-1							
74HCT151D			3.9 mm								
74HC151DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1							
74HCT151DB			body width 5.3 mm								
74HC151PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1							
74HCT151PW			body width 4.4 mm								



4. Functional diagram

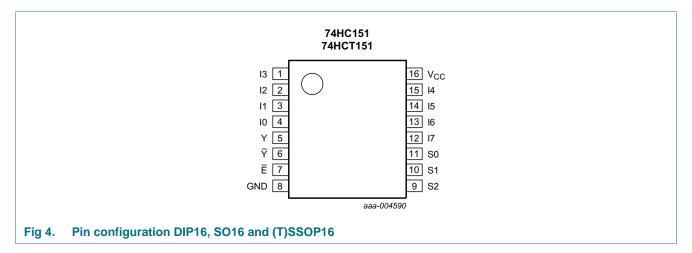




8-input multiplexer

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
10 to 17	4, 3, 2, 1, 15, 14, 13, 12	data inputs
Y	5	multiplexer output
Y	6	complementary multiplexer output
Ē	7	enable input (active LOW)
GND	8	ground (0 V)
S0, S1, S2	2 11, 10, 9	common data select inputs
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function table^[1]

Input												Outp	ut
E	S2	S1	S0	10	11	12	13	14	15	16	17	Y	Y
Н	Х	Х	Х	Х	Х	Х	Х	х	Х	Х	Х	Н	L
L	L	L	L	L	Х	Х	Х	Х	Х	Х	Х	Н	L
L	L	L	L	Н	Х	Х	Х	Х	Х	Х	Х	L	Н
L	L	L	Н	Х	L	Х	Х	Х	Х	Х	Х	Н	L
L	L	L	Н	Х	Н	Х	Х	Х	Х	Х	Х	L	Н
L	L	Н	L	Х	Х	L	Х	Х	Х	Х	Х	Н	L
L	L	Н	L	Х	Х	Н	Х	Х	Х	Х	Х	L	Н
L	L	Н	Н	Х	Х	Х	L	Х	Х	Х	Х	Н	L
L	L	Н	Н	Х	Х	Х	Н	Х	Х	Х	Х	L	Н
L	Н	L	L	Х	Х	Х	Х	L	Х	Х	Х	Н	L
L	Н	L	L	Х	Х	Х	Х	Н	Х	Х	Х	L	Н
L	Н	L	Н	Х	Х	Х	Х	Х	L	Х	Х	Н	L
L	Н	L	Н	Х	Х	Х	Х	Х	Н	Х	Х	L	Н
L	Н	Н	L	Х	Х	Х	Х	Х	Х	L	Х	Н	L
L	Н	Н	L	Х	Х	Х	Х	Х	Х	Н	Х	L	Н
L	Н	Н	Н	Х	Х	Х	Х	Х	Х	Х	L	Н	L
L	Н	Н	Н	Х	Х	Х	Х	Х	Х	Х	Н	L	Н

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

				10	,
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
I _{OK}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
lo	output current	V_{O} = -0.5 V to (V _{CC} + 0.5 V)	-	±25	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-	-50	mA
T _{stg}	storage temperature		-65	+150	°C

Table 4. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$			
	DIP16 package		<u>[1]</u> _	750	mW
	SO16 package		[2] _	500	mW
	(T)SSOP16 package		<u>[3]</u> _	500	mW

[1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 $^\circ C.$

[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 $^\circ\text{C}.$

[3] For SSOP16 and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 $^\circ$ C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter Conditions		74HC1	51		74HC	Unit		
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	− = − +85	40 °C to 5 °C		-40 °C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC15	1								1	
V _{IH}	HIGH-level	$V_{CC} = 2.0 V$	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	4.2	-	4.2	-	V
VIL	LOW-level	$V_{CC} = 2.0 V$	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	$V_{CC} = 4.5 V$	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O} = 20 \ \mu A; V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	-	±1.0	-	±1.0	μA
lcc	supply current		-	-	8.0	-	80	-	160	μA
CI	input capacitance		-	3.5	-					pF

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Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C		40 °C to 5 °C		-40 °C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HCT1	51					1	1		1	
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{ОН}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		$I_0 = -4 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current		-	-	8.0	-	80	-	160	μΑ
Δl _{CC}	additional supply current	$\label{eq:VL} \begin{array}{l} V_{I} = V_{CC} - 2.1 \text{ V};\\ \text{other inputs at } V_{CC} \text{ or GND};\\ V_{CC} = 4.5 \text{ V to 5.5 V};\\ I_{O} = 0 \text{ A} \end{array}$								
		per input pin; In inputs	-	45	162	-	203	-	221	μA
		per input pin; \overline{E} input	-	30	108	-	135	-	147	μA
		per input pin; Sn input	-	150	540	-	675	-	735	μA
CI	input capacitance		-	3.5	-					pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see Figure 7.

Symbol	Parameter	Conditions		T _{ar}	_{nb} = 25	°C		= –40 °C 85 °C		-40 °C 25 °C	Uni
				Min	Тур	Max	Min	Max	Min	Max	
For type	74HC151										
pd	propagation	In to Y; see Figure 5	<u>[1]</u>								
	delay	$V_{CC} = 2.0 V$		-	52	170	-	215	-	255	ns
		$V_{CC} = 4.5 V$		-	19	34	-	43	-	51	ns
		V _{CC} = 5 V; C _L = 15 pF		-	17	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	15	29	-	37	-	43	ns
		In to \overline{Y} ; see Figure 5	<u>[1]</u>								
		$V_{CC} = 2.0 V$		-	58	185	-	230	-	280	ns
		$V_{CC} = 4.5 V$		-	21	37	-	46	-	56	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	17	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	17	31	-	39	-	48	ns
		Sn to Y; see Figure 6	<u>[1]</u>								
		$V_{CC} = 2.0 V$		-	61	185	-	230	-	280	ns
		$V_{CC} = 4.5 V$		-	22	37	-	46	-	56	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	19	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	18	31	-	39	-	48	ns
		Sn to \overline{Y} ; see Figure 6	<u>[1]</u>								
		$V_{CC} = 2.0 V$		-	61	205	-	255	-	310	ns
		$V_{CC} = 4.5 V$		-	22	41	-	51	-	62	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	19	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	18	35	-	43	-	53	ns
		E to Y; see Figure 6									
		$V_{CC} = 2.0 V$		-	41	125	-	155	-	190	ns
		$V_{CC} = 4.5 V$		-	15	25	-	31	-	38	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	12	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	12	21	-	26	-	32	ns
		E to Y; see Figure 6									
		$V_{CC} = 2.0 V$		-	47	145	-	180	-	220	ns
		$V_{CC} = 4.5 V$		-	17	29	-	36	-	44	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	14	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	14	25	-	31	-	38	ns
t	transition	Y, Y; see Figure 5	[2]								
	time	$V_{CC} = 2.0 V$		-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 V$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 V$		-	6	13	-	16	-	19	ns

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Symbol	Parameter	Conditions	ons T _{amb} = 25 °C					= –40 °C 85 °C		: –40 °C ∣25 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	_
C _{PD}	power dissipation capacitance	C_L = 50 pF; f = 1 MHz; V _I = GND to V _{CC}	<u>[3]</u>	-	40	-	-	-	-	-	pF
For type	74HCT151										
t _{pd}	propagation	In to Y; see Figure 5	[1]								
	delay	$V_{CC} = 4.5 V$		-	22	38	-	48	-	57	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	19	-	-	-	-	-	ns
		In to \overline{Y} ; see Figure 5	<u>[1]</u>								
		$V_{CC} = 4.5 V$		-	22	38	-	48	-	57	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	19	-	-	-	-	-	ns
		Sn to Y; see Figure 6	<u>[1]</u>								
		$V_{CC} = 4.5 V$		-	23	41	-	51	-	62	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	20	-	-	-	-	-	ns
		Sn to \overline{Y} ; see Figure 6	<u>[1]</u>								
		$V_{CC} = 4.5 V$		-	25	43	-	54	-	65	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	20	-	-	-	-	-	ns
		E to Y; see Figure 6	<u>[1]</u>								
		$V_{CC} = 4.5 V$		-	16	29	-	36	-	44	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	13	-	-	-	-	-	ns
		\overline{E} to \overline{Y} ; see Figure 6	<u>[1]</u>								
		$V_{CC} = 4.5 V$		-	21	36	-	45	-	54	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	18	-	-	-	-	-	ns
tt	transition	Y, \overline{Y} ; see Figure 5	[2]								
	time	$V_{CC} = 4.5 V$		-	7	15	-	19	-	22	ns
C _{PD}	power dissipation capacitance	C_L = 50 pF; f = 1 MHz; V _I = GND to V _{CC}	<u>[3]</u>	-	40	-	-	-	-	-	pF

Table 7. Dynamic characteristics ... continued

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

[2] t_t is the same as t_{THL} and t_{TLH} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \sum (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$ f_i = input frequency in MHz; $f_o = output$ frequency in MHz;

 C_L = output load capacitance in pF;

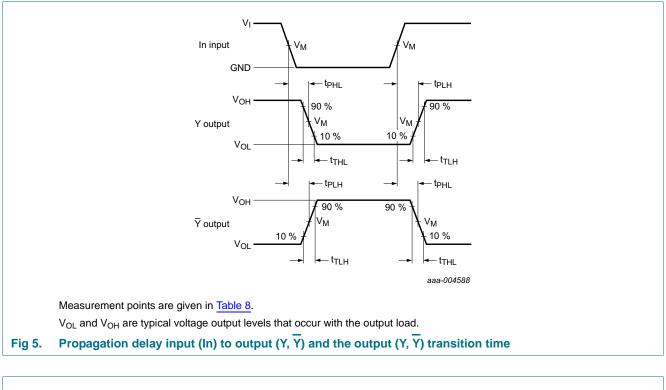
V_{CC} = supply voltage in V;

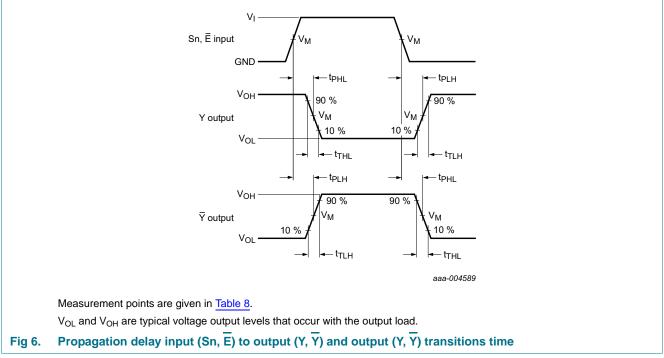
N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

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11. Waveforms





NXP Semiconductors

74HC151; 74HCT151

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Table 8. Measurement points		
Туре	Input	Output
	V _M	V _M
74HC151	0.5V _{CC}	0.5V _{CC}
74HCT151	1.3 V	1.3 V

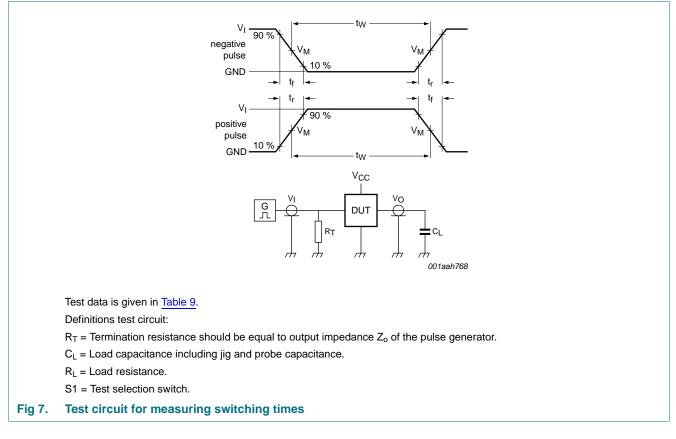


Table 9. Test data					
Туре	Input		Load	Test	
	VI	t _r , t _f	CL		
74HC151	V _{CC}	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}	
74HCT151	3.0 V	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}	

8-input multiplexer

12. Package outline

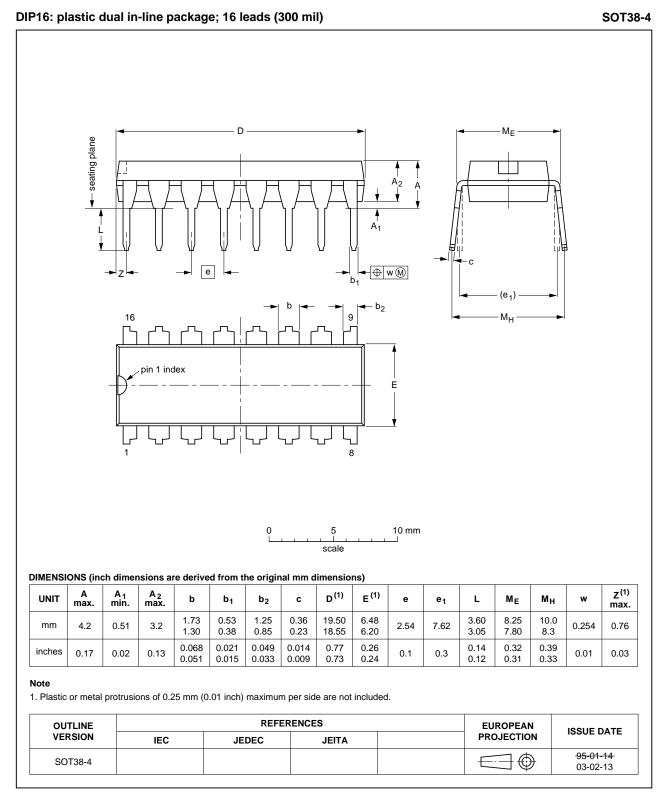


Fig 8. Package outline SOT38-4 (DIP16)

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8-input multiplexer

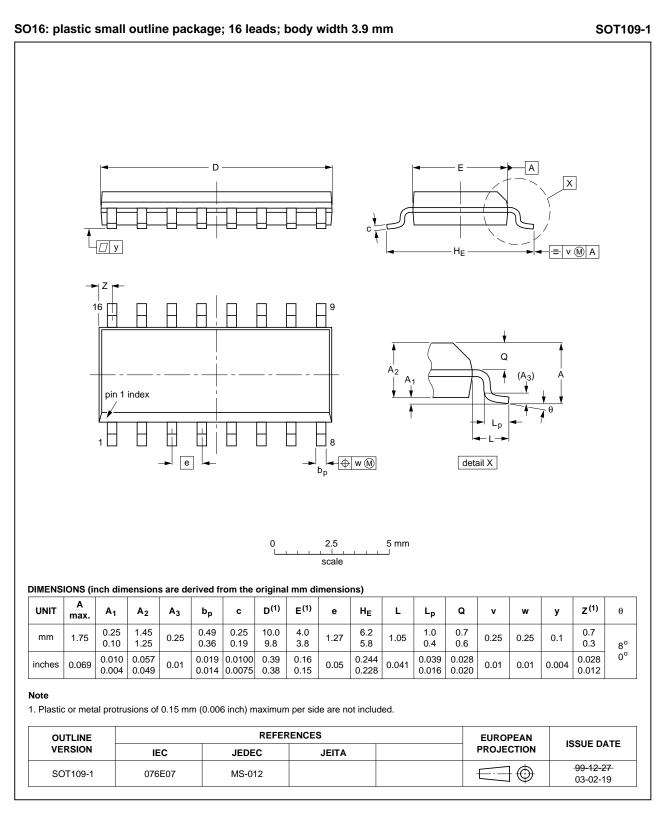


Fig 9. Package outline SOT109-1 (SO16)

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8-input multiplexer

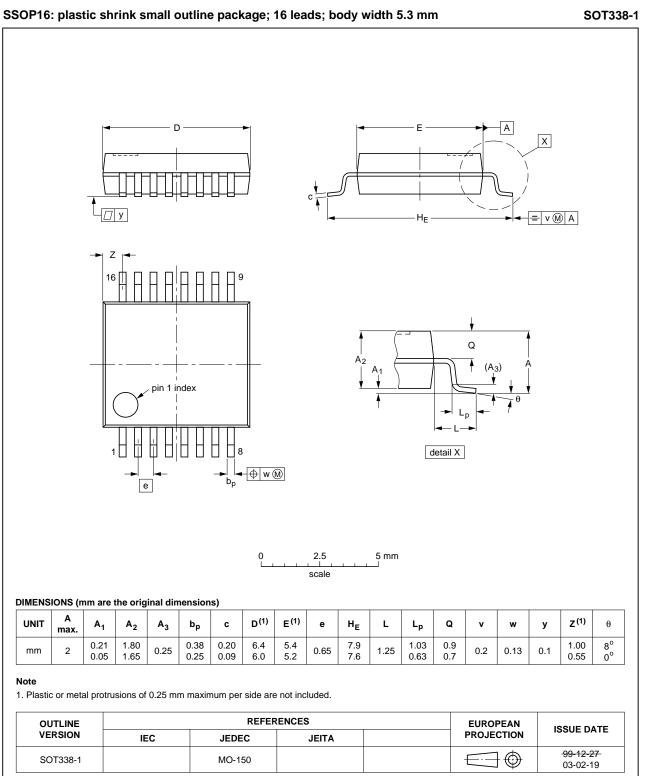


Fig 10. Package outline SOT338-1 (SSOP16)

8-input multiplexer

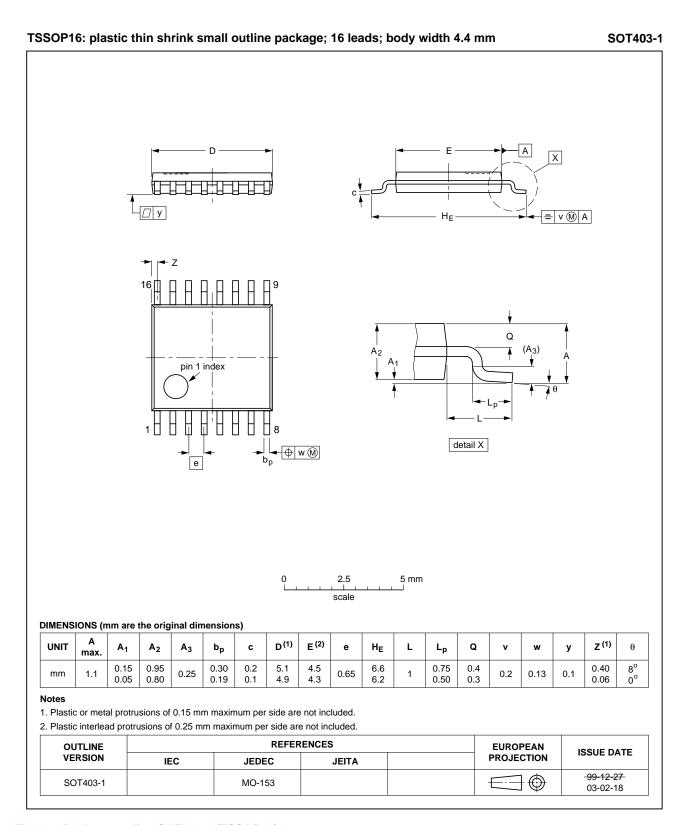


Fig 11. Package outline SOT403-1 (TSSOP16)

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13. Abbreviations

AcronymDescriptionCMOSComplementary Metal Oxide SemiconductorDUTDevice Under TestESDElectroStatic DischargeHBMHuman Body ModelMMMachine ModelTTLTransistor-Transistor LogicMUMilitary	Table 10. Abbreviations		
DUTDevice Under TestESDElectroStatic DischargeHBMHuman Body ModelMMMachine ModelTTLTransistor-Transistor Logic	Acronym	Description	
ESD ElectroStatic Discharge HBM Human Body Model MM Machine Model TTL Transistor-Transistor Logic	CMOS	Complementary Metal Oxide Semiconductor	
HBM Human Body Model MM Machine Model TTL Transistor-Transistor Logic	DUT	Device Under Test	
MM Machine Model TTL Transistor-Transistor Logic	ESD	ElectroStatic Discharge	
TTL Transistor-Transistor Logic	HBM	Human Body Model	
	MM	Machine Model	
MIL Militany	TTL	Transistor-Transistor Logic	
MIL MINUTY	MIL	Military	

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT151 v.4	20130211	Product data sheet	-	74HC_HCT151 v.3
Modifications:	 New descr 	iptive title (errata).		
74HC_HCT151 v.3	20120919	Product data sheet	-	74HC_HCT151_CNV v.2
74HC_HCT151_CNV v.2	19970827	Product specification	-	

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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